RoHS

COMPLIANT

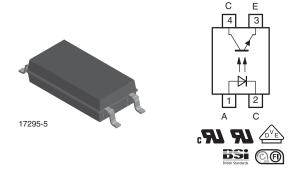
GREEN

(5-2008)



Vishay Semiconductors

Optocoupler, Phototransistor Output, SOP-4L, Long Mini-Flat Package



DESCRIPTION

The TCLT100. series consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4-lead SOP4L package.

APPLICATIONS

- Switchmode power supplies
- · Computer peripheral interface
- Microprocessor system interface

FEATURES

- SMD low profile 4 lead package
- V_{IORM} = 1050 V
- CTR flexibility available see order information
- Special construction
- Extra low coupling capacitance
- DC input with transistor output
- Creepage distance > 8 mm
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Note

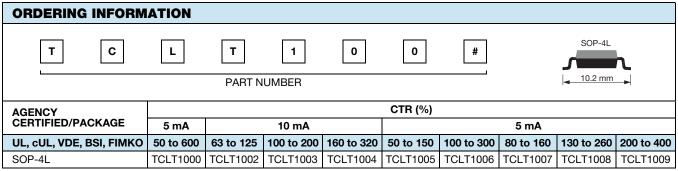
** Please see document "Vishay Material Category Policy": www.vishav.com/doc?99902

AGENCY APPROVALS

- UL1577, file no. E76222
- CSA (cUL) 22.2 bulletin 5A recognized file no. E-76222
- BSI: BS EN 41003, BS EN 60065 (BS 415), BS EN 60950 (BS 7002), certificate number 7081 and 7402
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending), available with option 1
- FIMKO (SETI): EN 60950

Note

 See the safety standard approval list "Agency Table" for more detailed information.



Note

· Available only on tape and reel.



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Reverse voltage		V _R	6	V				
Forward current		l _F	60	mA				
Forward surge current	t _p ≤ 10 μs	I _{FSM}	1.5	Α				
Power dissipation		P _{diss}	100	mW				
Junction temperature		T _j	125	°C				
OUTPUT								
Collector emitter voltage		V_{CEO}	70	V				
Emitter collector voltage		V _{ECO}	7	V				
Collector current		Ic	50	mA				
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA				
Power dissipation		P _{diss}	150	mW				
Junction temperature		Tj	125	°C				
COUPLER								
Isolation test voltage (RMS)		V _{ISO}	5000	V _{RMS}				
Total power dissipation		P _{tot}	250	mW				
Operating ambient temperature range		T _{amb}	- 55 to + 100	°C				
Storage temperature range		T _{stg}	- 55 to + 125	°C				
Soldering temperature		T _{sld}	260	°C				

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)										
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT				
INPUT	INPUT									
Forward voltage	$I_F = 50 \text{ mA}$	V _F		1.25	1.6	V				
Junction capacitance	$V_R = 0 V, f = 1 MHz$	C _j		50		pF				
OUTPUT										
Collector emitter voltage	$I_C = 1 \text{ mA}$	V_{CEO}	70			V				
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7			V				
Collector emitter cut-off current	$V_{CE} = 20 \text{ V}, I_F = 0 \text{ A}$	I _{CEO}		10	100	nA				
COUPLER										
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V _{CEsat}			0.3	V				
Cut-off frequency	V_{CE} = 5 V, I_F = 10 mA, R_L = 100 Ω	f _c		110		kHz				
Coupling capacitance	f = 1 MHz	C _k		0.3		pF				

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.



CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
	$V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$	TCLT1000	CTR	50		600	%	
	V _{CE} = 5 V, I _F = 10 mA	TCLT1002	CTR	63		125	%	
		TCLT1003	CTR	100		200	%	
I _C /I _F		TCLT1004	CTR	160		320	%	
	V _{CE} = 5 V, I _F = 1 mA	TCLT1002	CTR	22	45		%	
		TCLT1003	CTR	34	70		%	
		TCLT1004	CTR	56	100		%	
		TCLT1005	CTR	50		150	%	
	V _{CE} = 5 V, I _F = 5 mA	TCLT1006	CTR	100		300	%	
		TCLT1007	CTR	80		160	%	
		TCLT1008	CTR	130		260	%	
		TCLT1009	CTR	200		400	%	

SAFETY AND INSULATION RATED PARAMETERS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V_{pd}	2			kV	
Partial discharge test voltage -	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$	V _{IOTM}	8			kV	
lot test (sample test)	(see figure 2)	V_{pd}	1.68			kV	
	V _{IO} = 500 V	R _{IO}	10 ¹²			Ω	
Insulation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	10 ¹¹			Ω	
insulation resistance	V _{IO} = 500 V, T _{amb} = 150 °C (construction test only)	R _{IO}	10 ⁹			Ω	
Forward current		I _{si}	130			mA	
Power dissipation		P _{so}	265			mW	
Rated impulse voltage		V _{IOTM}	8			kV	
Safety temperature		T _{si}	150			°C	
Clearance distance			8.0			mm	
Creepage distance			8.0			mm	
Insulation distance (internal)			0.40			mm	

Note

• According to DIN EN 60747-5-2 (VDE 0884) (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

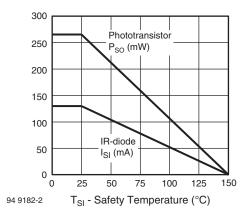


Fig. 1 - Derating Diagram

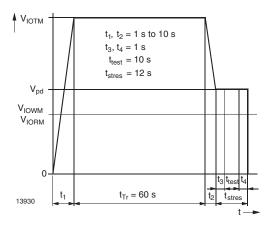


Fig. 2 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-2 (VDE 0884); IEC60747-5-5



SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Delay time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 3)	t _d		3		μs	
Rise time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _r		3		μs	
Fall time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _f		4.7		μs	
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 3)	t _s		0.3		μs	
Turn-on time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _{on}		6		μs	
Turn-off time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _{off}		5		μs	
Turn-on time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 4)	t _{on}		9		μs	
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 4)	t _{off}		10		μs	

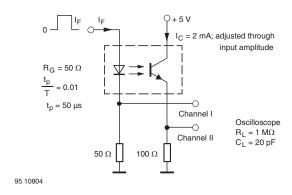


Fig. 3 - Test Circuit, Non-Saturated Operation

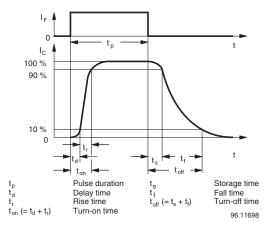


Fig. 5 - Switching Times

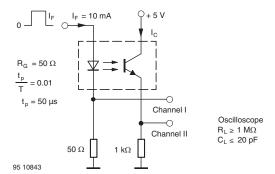
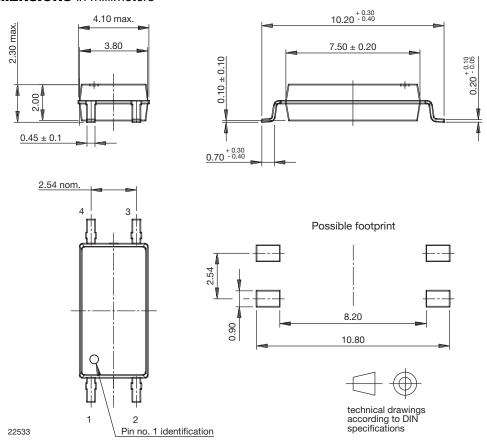


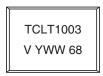
Fig. 4 - Test Circuit, Saturated Operation



PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING





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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.